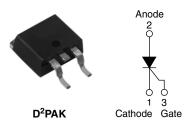




Vishay High Power Products

Surface Mountable Phase Control SCR, 16 A



PRODUCT SUMMARY			
V _T at 16 A < 1.25 V			
I _{TSM}	300 A		
V_{RRM}	800 V to 1600 V		

DESCRIPTION/FEATURES

The 25TTS...SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.



COMPLIANT

HALOGEN FREE

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches

used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package

outlines.

This product has been designed and qualified for industrial

level.

Compliant to RoHS directive 2002/95/EC.

Halogen-free according to IEC 61249-2-21 definition.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS			
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	3.5	5.5		
Aluminum IMS, R _{thCA} = 15 °C/W	8.5	13.5] A	
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	16.5	25.0		

Note

• $T_A = 55 \,^{\circ}\text{C}$, $T_J = 125 \,^{\circ}\text{C}$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform 16		۸	
I _{RMS}		25	Α	
V _{RRM} /V _{DRM}		800 to 1600	V	
I _{TSM}		300	Α	
V _T	16 A, T _J = 25 °C	1.25	V	
dV/dt		500	V/μs	
dl/dt		150	A/μs	
T _J		- 40 to 125	°C	

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK ART NUMBER REVERSE VOLTAGE V		I _{RRM} /I _{DRM} , AT 125 °C mA			
25TTS08SPbF	800	800				
25TTS12SPbF 1200 1200			10			
25TTS16SPbF	1600	1600				

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES		UNITS
PARAMETER	STINIBUL	155	TEST CONDITIONS		MAX.	UNITS
Maximum average on-state current	$I_{T(AV)}$	T _C = 93 °C, 180° conduction half sine wave		1	6	
Maximum RMS on-state current	I _{RMS}			2	.5	Α
Maximum peak, one-cycle,	-	10 ms sine pulse, rat	ted V _{RRM} applied	30	00	_ ^
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no	voltage reapplied	3	50	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rat	ted V _{RRM} applied	450		- A ² s
Maximum i-t for fusing	I-t	10 ms sine pulse, no	voltage reapplied	6	30	A-S
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		63	800	A ² √s
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.	25	٧
On-state slope resistance	r _t	T ₁ = 125 °C		12	2.0	mΩ
Threshold voltage	$V_{T(TO)}$			1	.0	٧
Maximum rayarea and direct lookage current	1 /1	T _J = 25 °C	V - Potod V /V	0.5		
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	$V_R = Rated V_{RRM}/V_{DRM}$		0	
Holding ourront	I _H	25TTS08, 25TTS12	Anode supply = 6 V, resistive load, initial I _T = 1 A	-	100	mA
Holding current		25TTS16		100	150	
Maximum latching current	ΙL	Anode supply = 6 V, resistive load 200		00		
Maximum rate of rise of off-state voltage	dV/dt	500		V/µs		
Maximum rate of rise of turned-on current	dl/dt	150		50	A/μs	

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS VA		UNITS	
Maximum peak gate power	P_{GM}		8.0	W	
Maximum average gate power	$P_{G(AV)}$		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	V	
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45		
		Anode supply = 6 V, resistive load, T _J = 125 °C	20		
	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5		
Maximum required DC gate voltage to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V	
to ingge.		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}, V_{\text{DRM}} = \text{Rated value}$ 0.25			
Maximum DC gate current not to trigger	I _{GD}			mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T 105 °C	4	μs
Typical turn-off time	tq	T _J = 125 °C	110	



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THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Soldering temperature	T _S	For 10 s (1.6 mm from case)	240	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} (1)		40	0/11
Approximate weight			2	g
Approximate weight			0.07	OZ.
			25TTS08S	
Marking device		Case style D ² PAK (SMD-220)	25TTS1	2S
			25TTS1	6S

Note

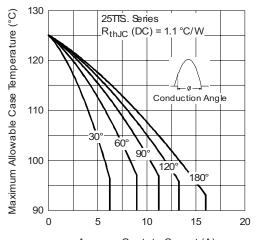
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 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 $\mu m]$ copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

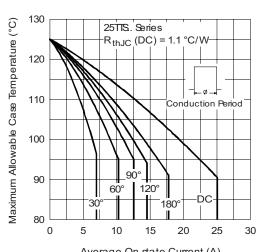
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Average On-state Current (A)
Fig. 1 - Current Rating Characteristics



Average On-state Current (A)
Fig. 2 - Current Rating Characteristics

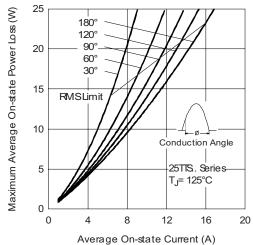


Fig. 3 - On-State Power Loss Characteristics

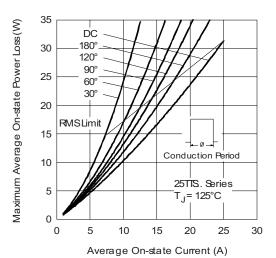


Fig. 4 - On-State Power Loss Characteristics

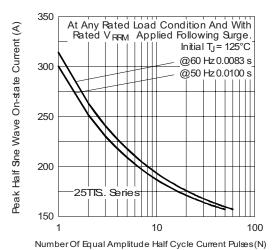


Fig. 5 - Maximum Non-Repetitive Surge Current

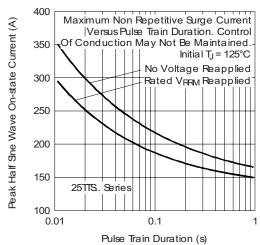


Fig. 6 - Maximum Non-Repetitive Surge Current



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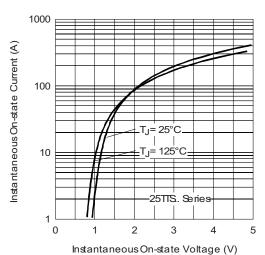
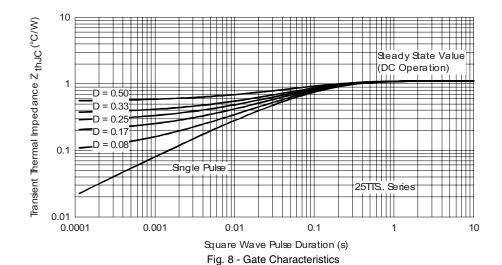


Fig. 7 - On-State Voltage Drop Characteristics



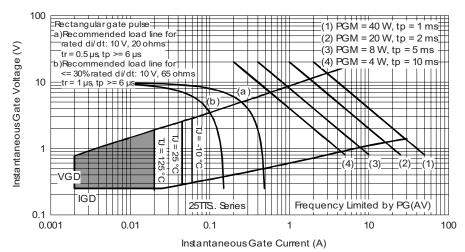


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

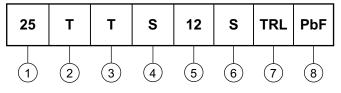
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ORDERING INFORMATION TABLE

Device code



1 - Current rating (25 = 25 A)

2 - Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AC

4 - Type of silicon:

Standard recovery rectifier

08 = 800 V 12 = 1200 V

Voltage rating = Voltage code x 100 = V_{RRM}

12 - 1200 V 16 - 1600 V

- S = TO-220 D²PAK (SMD-220) version

16 = 1600 V

7 - • None = Tube

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95046</u>				
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			

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